

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MBRT120150 thru MBRT120200R

Three Tower Package

Silicon Power Schottky Diode

 $V_{RRM} = 150 V - 200 V$

 $I_{F(AV)} = 120 A$

Features

- High Surge Capability
- \bullet Types from 150 V to 200 V V_{RRM}
- Isolation Type Package
- Electrically Isolated Base Plate
- Not ESD Sensitive

LUG Teminal Teminal Teminal Teminal Teminal Cathode 2 Anode 3 Cathode 1 Anode 2 Cathode 3 Common Center Common Cathode & N-Type LUG LUG Teminal Teminal Teminal Cathode 3 Cathode 3 Common Center R=Common Anode & P-Type

Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

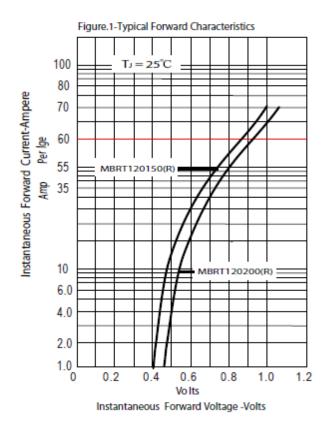
Parameter	Symbol	Conditions	MBRT120150(R)	MBRT120200(R)	Unit
Repetitive peak reverse vo	oltage V _{RRM}		150	200	V
RMS reverse voltage	V_{RMS}		106	141	V
DC blocking voltage	V _{DC}		150	200	V
Operating temperature	Tj		-55 to 150	-55 to 150	°C
Storage temperature	T _{stg}		-55 to 150	-55 to 150	°C

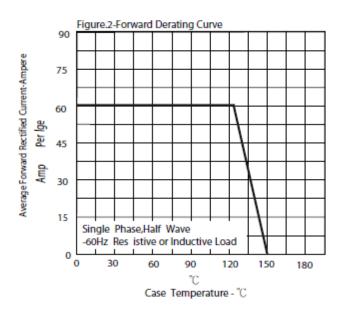
Electrical characteristics, at Tj = 25 °C, unless otherwise specified

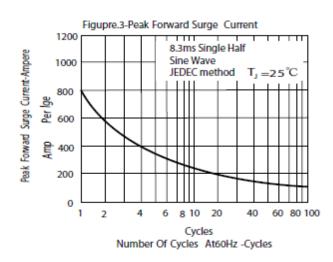
Parameter	Symbol	Conditions	MBRT120150(R)	MBRT120200(R)	Unit
Average forward current (per pkg)	I _{F(AV)}	T _C = 125 °C	120	120	А
Peak forward surge current (per leg)	I _{FSM}	t_p = 8.3 ms, half sine	800	800	А
Maximum instantaneous forward voltage (per leg)	V_{F}	I _{FM} = 60 A, T _j = 25 °C	0.88	0.92	V
Maximum instantaneous		T _j = 25 °C	1	1	
reverse current at rated DC	I_R	T _i = 100 °C	10	10	mA
blocking voltage (per leg)		T _j = 150 °C	30	30	
Thermal characteristics					
Thermal resistance, junction- case (per leg)	$R_{\Theta JC}$		0.80	0.80	°C/W

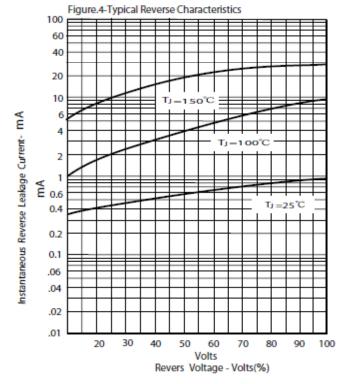


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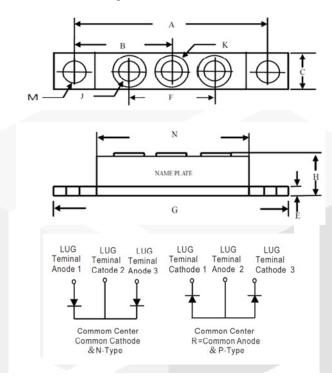




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Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIM	Inc	hes	Millimeters				
	Min	Max	Min	Max			
Α	3.150	NOM	80.01	NOM			
В	1.565	1.585	39.75	40.26			
С	.700	.800	17.78	20.32			
Е	.119	.132	3.02	3.35			
F	1.327	REF	33.72	REF			
G	3.55	3.65	90.17	92.71			
Н		.73		18.30			
J	1/4-20 UNC FULL						
K	.472	.511	12	13			
М	.275	.295	6.99	7.49			
N	2.38	2.46	60.5	62.5			